RoHS

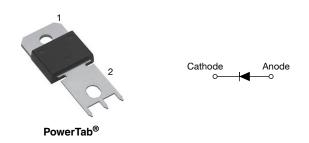
COMPLIANT

HALOGEN FREE



### Vishay Semiconductors

# Ultrafast Soft Recovery Diode, 80 A FRED Pt®



#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	80 A				
V <sub>R</sub>	400 V				
V <sub>F</sub> at I <sub>F</sub>	0.92 V				
t <sub>rr</sub> (typ.)	See recovery table				
T <sub>J</sub> max.	175 °C				
Package	PowerTab <sup>®</sup>				
Circuit configuration	Single				

#### **FEATURES**

- · Ultrafast recovery time
- 175 °C max. operating junction temperature
- Screw mounting only
- Designed and qualified according to JEDEC®-JESD 47
- PowerTab<sup>®</sup> package
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

### **BENEFITS**

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

### **DESCRIPTION / APPLICATIONS**

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

#### **MECHANICAL DATA**

Case: PowerTab®

Molding compound meets UL 94 V-0 flammability rating

Terminal: nickel plated, screwable

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	$V_R$		400	V
Continuous forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 101 °C	80	
Single pulse forward current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	800	Α
Maximum repetitive forward current	I <sub>FRM</sub>	Square wave, 20 kHz	160	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	$I_{R} = 100 \mu A$	400	1	-	
		$I_F = 80 \text{ A}$	ı	1.1	1.3	V
Forward voltage V <sub>F</sub>	I <sub>F</sub> = 80 A, T <sub>J</sub> = 175 °C	-	0.92	1.08	ď	
		I <sub>F</sub> = 80 A, T <sub>J</sub> = 125 °C		0.98	1.15	
Poverse leekege overent	I_	$V_R = V_R$ rated	-	-	50	μA
Reverse leakage current I <sub>R</sub>		$T_J = 150  ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	-	2	mA
Junction capacitance	C <sub>T</sub>	$V_{R} = 200 \text{ V}$	-	50	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	3.5	-	nH



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		I <sub>F</sub> = 1 A, dI <sub>F</sub> /dt = 200 /	4/μs, V <sub>R</sub> = 30 V	-	50	60	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	87	-	ns
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 80 A V <sub>B</sub> = 200 V	-	151	-	
Peak recovery current I <sub>RRM</sub>	ı	T <sub>J</sub> = 25 °C		-	9.3	-	Α
	T <sub>J</sub> = 125 °C	v <sub>R</sub> = 200 v dl <sub>F</sub> /dt = 200 A/µs	-	17.2	-		
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	405	-	nC
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1300	-	IIC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.70	°C/W
Thermal resistance, junction to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.2	-	C/VV
Weight			-	-	5.02	g
Mounting torque			1.2		2.4	N·m
Wounting torque			(10)	_	(20)	(lbf · in)
Marking device		Case style PowerTab® 80EBU04				

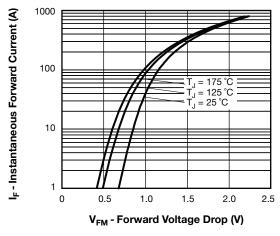


Fig. 1 - Maximum Forward Voltage Drop Characteristics

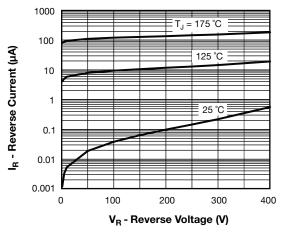


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

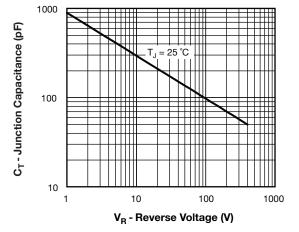


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



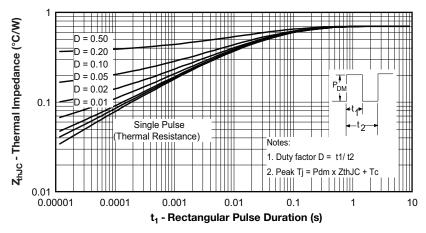


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

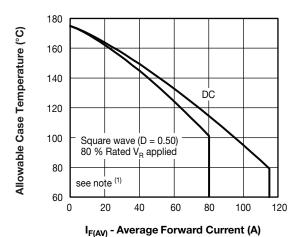


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

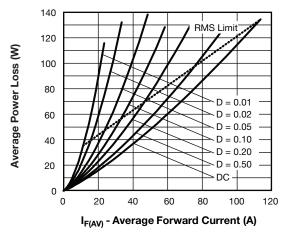


Fig. 6 - Forward Power Loss Characteristics

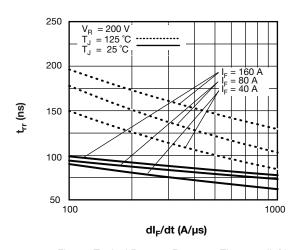


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

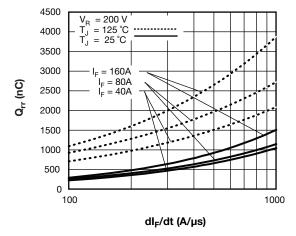
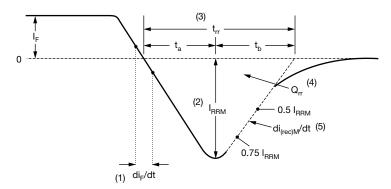


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

<sup>&</sup>lt;sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D) (see fig. 6)$ ;  $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80 \%$  rated  $V_R$ 

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- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RBM</sub> and 0.50 I<sub>RBM</sub> extrapolated to zero current.
- (4)  $\rm Q_{rr}$  area under curve defined by  $\rm t_{rr}$  and  $\rm I_{RRM}$

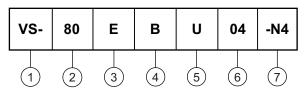
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 9 - Reverse Recovery Waveform and Definitions

#### **ORDERING INFORMATION TABLE**

**Device code** 



- Vishay Semiconductors product
- 2 Current rating (80 = 80 A)
- 3 E = Single diode
- 4 B = PowerTab<sup>®</sup> (ultrafast/hyperfast only)
- 5 U = Ultrafast recovery
- 6 Voltage rating (04 = 400 V)
- 7 Environmental digit:

-N4 = Halogen-free, RoHS-compliant and totally lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION		
VS-80EBU04-N4	25/tube	Antistatic plastic tube		

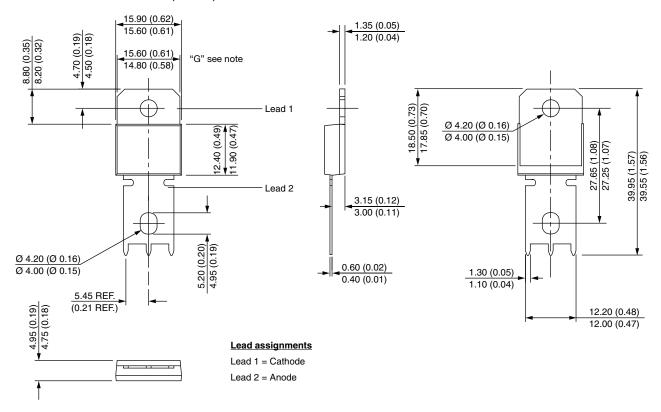
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95240			
Part marking information	www.vishay.com/doc?95467			
Application note	www.vishay.com/doc?95179			



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### PowerTab®

### **DIMENSIONS** in millimeters (inches)



#### Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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